

# 8200LN Rubidium Oscillator



### **Key Features**

- 10 MHz Output
- 1 PPS Output
- 1 PPS Input
- Low Phase Noise
- Low Physical Profile (< 1.0" high)
- Low Weight <2 lbs.
- Digital Monitor and Control
- Shock/Vibration Hardened

### **Optional Features:**

- 5 MHz Output
- Low-g sensitivity

### **Key Benefits:**

- Superior frequency stability
- Diverse environmental conditions support

The Microsemi<sup>®</sup> 8200LN is a ruggedized rubidium oscillator designed for ground tactical, shipboard and airborne applications where superior frequency stability under diverse environmental conditions is required. Advanced communications, navigation and targeting systems require precision oscillators that can withstand a wide range of operating environments with minimal degradation in frequency accuracy and stability. The 8200LN support these applications with superior phase noise and excellent short and long term frequency stability.

The 8200LN is unique in that it combines excellent frequency stability and low dynamic phase noise in a small, low profile package measuring less than 1.0 inches high and weighing less than 2 lbs. The standard performance 8200LN provides both 10MHz and 1PPS outputs along with a 1PPS input for disciplining to a GPS receiver or other primary standard. Optional configurations can support additional outputs or custom outputs. When equipped with an optional low g sensitivity crystal, the 8200LN can maintain low phase noise performance over a wide range of vibration profiles. The 8200LN is designed around proven rubidium and OCXO technology that has been deployed in numerous airborne, shipboard and ground tactical platforms for over thirty years.

## 8200LN

### **Specifications**

Rise Time:

P

### **ELECTRICAL SPECIFICATIONS**

•	RF Output
	Frequency:
	Format:
	Amplitude:
	VSWR
	Harmonic Distortion
	Non-harmonic Distortion
	Load Impedance:
	Connector:
	Qty:
,	1PPS Output

Distortion e:	< -80 dBc 50 ohms @ 10MHz SMA Female 2
	<5 ns <400 ns +/-10% >3 Vdc TTL Compatible

10 MHz (nominal)

+10 dBm ±2 dBm (0.7 V rms nominal)

Sinewave

1.5:1 < -30 dBc

Pulse Width:	<400 ns +/-10%		
Level:	>3 Vdc TTL Compatib		
Jitter:	<10 ps RMS		
Output Impedance:	50 ohms		
Connector:	SMA Female		
Qty:	2		

### PERFORMANCE PARAMETERS

<ul> <li>Phase noise (SSB), £(f), dBc/Hz (St</li> </ul>	atic)					
SB Freq	10 MHz	5 MHz				
1 Hz	<-98	<-103				
10 Hz	<-130	<-135				
100 Hz	<-148	<-153				
1 KHz	<-154	<-155				
10 KHz	<-157	<-157				
<ul> <li>Spectral purity</li> </ul>						
Harmonics:	<-40 dBc					
Non-harmonics:	<-80 dBc					
• Aging						
Monthly (after 1 month):	<±5.0E-11					
• Frequency accuracy at shipment:	<±5.0E-11 (@ +25° C)					
Frequency retrace	<±5.0E-11 (on-off-on 24 hours @ 25°C)	: 24 hours, 24 hours,				
• Short term stability σy (τ) (Allan deviation)						
т (sec)						
т (sec)						
т (sec) 1	<1.4E-11					
τ (sec) 1 10	<1.4E-11 <7.0E-12					
τ (sec) 1 10 100	<1.4E-11 <7.0E-12 <2.5E-12					
τ (sec) 1 10 100 • Frequency control	<1.4E-11 <7.0E-12 <2.5E-12					
τ (sec) 1 10 100 • Frequency control Analog freq. adj. range:	<1.4E-11 <7.0E-12 <2.5E-12 +/-1.5E-9, 0 - 5V into (optional)	5Kohm impedance				
r (sec) 1 10 100 • Frequency control Analog freq. adj. range: Digital freq. adj. res:	<1.4E-11 <7.0E-12 <2.5E-12 +/-1.5E-9, 0 - 5V into (optional) +/-1.0E-6 with 1.0E-1	5Kohm impedance 2 resolution				
т (sec) 1 10 100 • Frequency control Analog freq. adj. range: Digital freq. adj. res: Warm-up times	<1.4E-11 <7.0E-12 <2.5E-12 +/-1.5E-9, 0 - 5V into (optional) +/-1.0E-6 with 1.0E-1 -40° C	5Kohm impedance 2 resolution +25°				
т (sec) 1 10 100 • Frequency control Analog freq. adj. range: Digital freq. adj. res: Warm-up times Time to lock:	<1.4E-11 <7.0E-12 <2.5E-12 +/-1.5E-9, 0 - 5V into (optional) +/-1.0E-6 with 1.0E-1 -40° C <8 min	5Kohm impedance 2 resolution +25° <6 min				

Warm-up times	-40° C	+25°		(1) DB-9 (All mor
Time to lock:	<8 min	<6 min	Reliability Specification:	MIL-HDBK-217F
Time to <1E-9:	<10 min	<8 min	Dimensions	
Power Consumption @ 28V:	<28W	<28W	Height:	0.95"
			Width:	6.13"
Input voltage range:	+15 to 32 Vdc		Depth:	5.52"
(Protected against reverse polar	ity & transients)	Volume:	32.2 in3	
Voltage sensitivity:	<5.0E-12 Vdc		Weight:	<2.0 lbs

(±10% voltage change from nom. 28 Vdc Input)



Microsemi Corporation (Nasdaq: MSCC) offers a comprehensive portfolio of semiconductor solutions for aerospace, defense and security; enterprise and communications; and industrial and alternative energy markets. Products include high-performance, high-reliability analog and RF devices, mixed signals and RF integrated circuits, customizable SoCs, FPGAs, and complete subsystems. Microsemi is headquartered in Aliso Viejo, Calif. Learn more at www.microsemi.com

• Input power, quiescent: +28 Vdc @ -40° C baseplate

• Lock Status (BITE)

• Temperature

Operating:

Storage:

Altitude

• Salt fog:

• Shock:

• MTBF:

• Vibration:

Operating:

Operating:

• EMI MIL-STD-461 Emissions:

Susceptibility:

• Reliability Specification:

• Input Connector:

Non-Operating:

Non-Operating:

TTL low = Lock

TTL high = Unlock • RS-232 control/monitor interface

Frequency Sensitivity:

• Orientation sensitivity: • Pressure sensitivity:

> Operating: Non-operating:

• Thermal shock (non-operating):

• Relative humidity (operating):

• Magnetic field sensitivity: (DC field, ≤2 Gauss)

+28 Vdc @ +25° C baseplate

+28 Vdc @ +75° C baseplate

<20W

<15W

<11W

Provides ID, status/monitor information, and frequency/operating parameter

-40° C to +75° C baseplate

<3.0E-10 over op. temp. range

Sea level to 40,000' (12,192 m)

Sea level to 80,000' (24,384 m)

MIL-STD-810, Method 509.4

Hz -1KHz, 30 min/axis

CE102, RE102 CS101, CS114, RS103

MIL-HDBK-217F

• On-Off cycling endurance: 5000 cycles at 10° C baseplate

MIL-STD-202, Method 213

50g, 11ms, half-sine impulse

70,000 hours (ground fixed) @ +40° C baseplate

(1) DB-9 (All input power) (1) DB-9 (All monitoring)

0 to 95% RH per MIL-STD-810, Method 507.4

Hz -1KHz, 15 min/axis (maintain frequency lock)

Category 24, Minimum Integrity, 7.7 grms @ 0.04 g/Hz, 20

Category 24, Minimum Integrity, 15.4 grms @ 0.16 g/Hz, 20

30g, 11ms, half-sine impulse (maintain frequency lock)

MIL-STD-810, Method 514.5, Procedure I

-55° C to +95° C

<1.0E-13/mbar

≤ ±4.0E-11/Gauss

MIL-STD-202, Method 107, Test Condition A, 10 cycles -55° C to 85° C <5.0E-11 for any orientation

adjustments. Protocol: 9600, 8, 1, None, No flow control.

**ENVIRONMENTAL & PHYSICAL SPECIFICATIONS** 

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